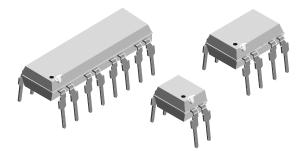
End of Life June-2024

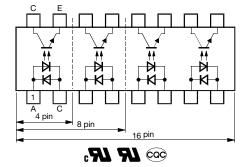


K814P, K824P, K844P

Vishay Semiconductors

Optocoupler, Phototransistor Output, AC Input





LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The K814P, K824P, K844P consist of a phototransistor optically coupled to 2 gallium arsenide infrared emitting diodes (reverse polarity) in 4 pin (single); 8 pin (dual) or 16-pin (quad) plastic dual inline package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

FEATURES

- Endstackable to 2.54 mm (0.1") spacing
- DC isolation test voltage V_{ISO} = 5000 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- Current transfer ratio (CTR) of typical 100 %
- Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Feature phones
- Answering machines
- PBX
- Fax machines

AGENCY APPROVALS

- <u>UL</u>
- <u>cUL</u>
- <u>CQC</u>

ORDERING INFORMATION	
К 8	# 4 P
PART	NUMBER
AGENCY CERTIFIED / PACKAGE	CTR (%)
UL, cUL	> 20
DIP-4, single channel	K814P
DIP-8, dual channel	K824P
DIP-16, quad channel	K844P



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	CONDITION	SYMBOL	VALUE	UNIT			
INPUT			•				
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	A			
Power dissipation		P _{diss}	100	mW			
Junction temperature		Тj	125	°C			
OUTPUT			•				
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ι _C	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		Tj	125	°C			
COUPLER							
AC isolation test voltage (RMS)	t = 1.0 min	V _{ISO}	5000	V _{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	-40 to +100	°C			
Storage temperature range		T _{stg}	-55 to +125	°C			
Soldering temperature ⁽¹⁾	2 mm from case, t \leq 10 s	T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 50 mA	V _F	-	1.25	1.6	V	
Reverse current	$V_{R} = \pm 6 V$	I _R	-	-	10	μA	
OUTPUT							
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	70	-	-	V	
Emitter collector breakdown voltage	I _E = 10 μA	BV _{ECO}	7	-	-	V	
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}	-	-	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_{\rm F} = \pm 10$ mA, $I_{\rm C} = 1$ mA	V _{CEsat}	-	-	0.3	V	
Cut-off frequency	I_{F} = ± 10 mA, V_{CE} = 5 V, R_{L} = 100 Ω	f _c	-	100	-	kHz	
Coupling capacitance	f = 1 MHz	C _k	-	0.3	-	pF	

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$	K814P	CTR	20	-	300	%

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SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	V_S = 5 V, I _C = 2 mA, R _L = 100 Ω (see Fig. 1)	t _d	-	3	-	μs
Rise time	V_{S} = 5 V, I_{C} = 2 mA, R_{L} = 100 Ω (see Fig. 1)	t _r	-	3	-	μs
Fall time	V_{S} = 5 V, I_{C} = 2 mA, R_{L} = 100 Ω (see Fig. 1)	t _f	-	4.7	-	μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	ts	-	0.3	-	μs
Turn-on time	V_{S} = 5 V, I_{C} = 2 mA, R_{L} = 100 Ω (see Fig. 1)	t _{on}	-	6	-	μs
Turn-off time	V_{S} = 5 V, I_{C} = 2 mA, R_{L} = 100 Ω (see Fig. 1)	t _{off}	-	5	-	μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 10 \text{ mA}, R_L = 1 \text{ k}\Omega \text{ (see Fig. 1)}$	t _{on}	-	9	-	μs
Turn-off time	$V_{S} = 5 \text{ V}, \text{ I}_{C} = 10 \text{ mA}, \text{ R}_{L} = 1 \text{ k}\Omega \text{ (see Fig. 1)}$	t _{off}	-	18	-	μs

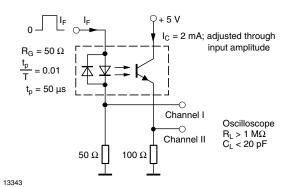


Fig. 1 - Test Circuit, Non-Saturated Operation

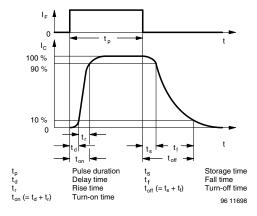


Fig. 3 - Switching Times

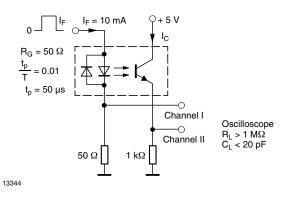


Fig. 2 - Test Circuit, Saturated Operation

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

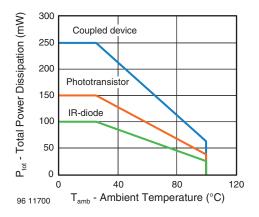


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

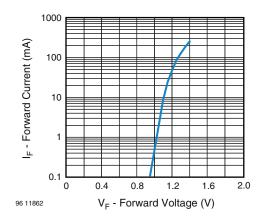


Fig. 5 - Forward Current vs. Forward Voltage

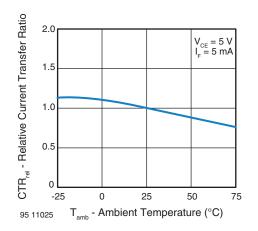


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

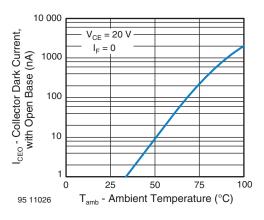


Fig. 7 - Collector Dark Current vs. Ambient Temperature

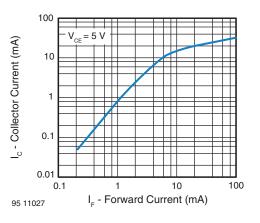


Fig. 8 - Collector Current vs. Forward Current

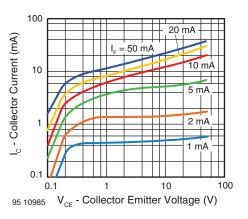


Fig. 9 - Collector Current vs. Collector Emitter Voltage

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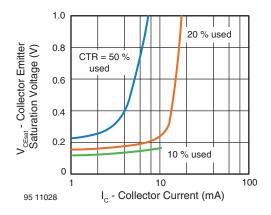


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

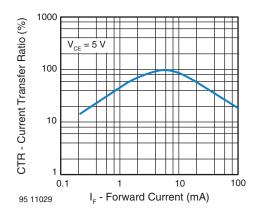


Fig. 11 - Current Transfer Ratio vs. Forward Current

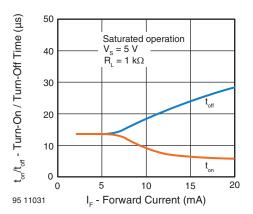


Fig. 12 - Turn-on / Turn-off Time vs. Forward Current

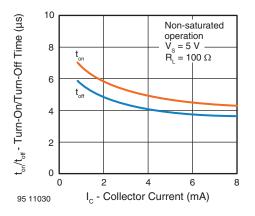


Fig. 13 - Turn-on / Turn-off Time vs. Collector Current

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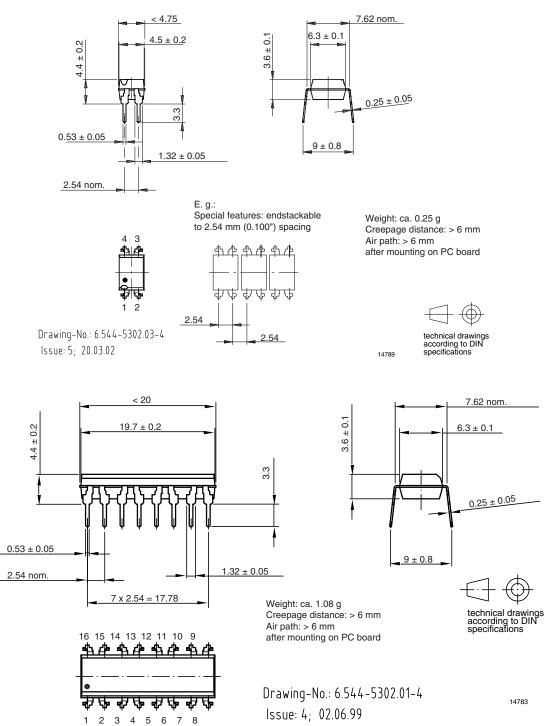


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PACKAGE DIMENSIONS in millimeters

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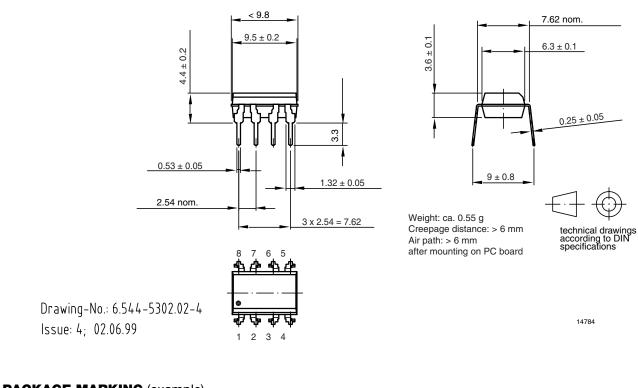
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PACKAGE MARKING (example)



Note

• XXXX = LMC (lot marking code)



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